

Electronic Supplementary Information (ESI)

Exceptional electronic and mechanical properties in HfN₂ monolayer: promising candidate in low-power nano, flexible electronics, memory devices and photocatalysis

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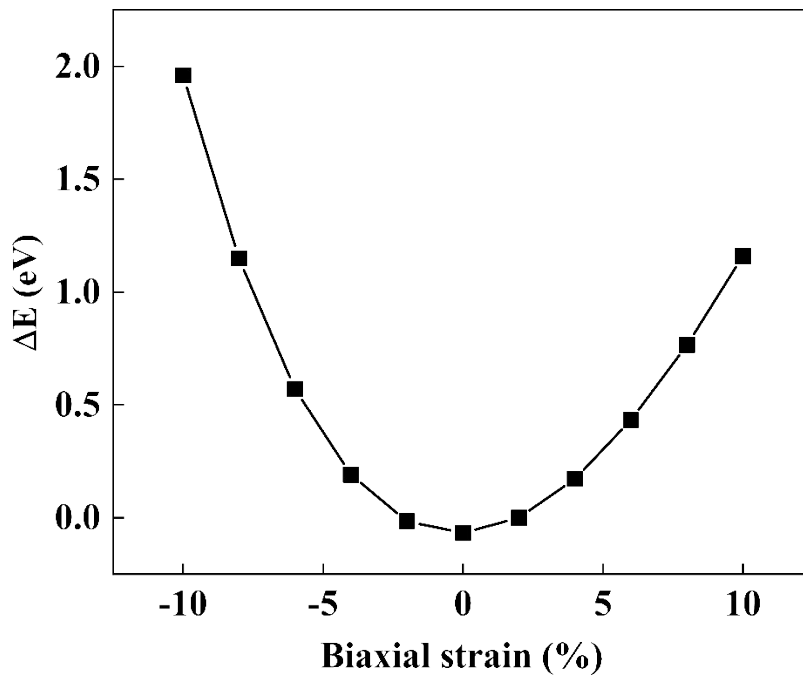


Figure S1. Strain-energy curve under biaxial strain applied within $\pm 10\%$.